### Schottky Rectifier, 5.5 A

#### **FEATURES**

- · Low forward voltage drop
- Guard ring for enhanced ruggedness and long RoHS term reliability COMPLIANT
- Halogen-free according to IEC 61249-2-21 FREE definition
- Popular D-PAK outline
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS Directive 2002/95/EC

### DESCRIPTION

The VS-50WQ03FN-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I <sub>F(AV)</sub>	Rectangular waveform	5.5	А						
V <sub>RRM</sub>		30	V						
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	320	А						
V <sub>F</sub>	5 Apk, T <sub>J</sub> = 125 °C	0.35	V						
TJ	Range	- 40 to 150	°C						

VOLTAGE RATINGS									
PARAMETER	VS-50WQ03FN-M3	UNITS							
Maximum DC reverse voltage	V <sub>R</sub>	- 30	V						
Maximum working peak reverse voltage	V <sub>RWM</sub>		v						

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	VALUES	UNITS						
Maximum average forward current $I_{F(AV)}$ 50 % duty cycle at T <sub>C</sub> = 136 °C, rectangular waveform		, rectangular waveform	5.5	А				
Maximum peak one cycle non-repetitive surge current	l	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	320	A			
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	rated V <sub>RRM</sub> applied	130				
Non-repetitive avalanche energy	E <sub>AS</sub>	$T_J = 25 \text{ °C}, I_{AS} = 2 \text{ A}, L = 5 \text{ mH}$		10	mJ			
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		2.0	А			

Base cathode

Ó 1

Anode

Q 4, 2

D-PAK (TO-252AA)

5.5 A

30 V

See Electrical table

58 mA at 125 °C

150 °C

Single die

10 mJ

ÓЗ

Anode

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**D-PAK (TO-252AA)** 

**PRODUCT SUMMARY** 

Package

I<sub>F(AV)</sub>

 $\mathsf{V}_\mathsf{R}$ 

V<sub>F</sub> at I<sub>F</sub>

 $I_{RM}$ 

T<sub>J</sub> max.

Diode variation

 $\mathsf{E}_{\mathsf{AS}}$ 



# VS-50WQ03FN-M3

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Schottky Rectifier, 5.5 A



ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
		5 A	T <sub>.1</sub> = 25 °C	0.46				
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	10 A	$1_{\rm J} = 25$ C	0.53	V			
See fig. 1		5 A	T.I = 125 °C	0.35				
		10 A	1j = 125 C	0.46				
Maximum reverse leakage current	I <sub>BM</sub> <sup>(1)</sup>	$T_J = 25 \ ^\circ C$	$V_{\rm B} = \text{Rated } V_{\rm B}$	3	mA			
See fig. 2	IRM \	T <sub>J</sub> = 125 °C	VR - naleu VR	58				
Threshold voltage	V <sub>F(TO)</sub>			0.19	V			
Forward slope resistance	$T_J = T_J$ maximum			22.22	mΩ			
Typical junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal range	590	pF				
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 n	5.0	nH				

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER SYMBOL TEST CONDITIONS VALUES UNITS										
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		- 40 to 150	°C						
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation See fig. 4	3.0	°C/W						
Approximate weight			0.3	g						
Approximate weight			0.01	oz.						
Marking device		Case style D-PAK (similar to TO-252AA)	50WQ03FN							

#### Note

(1)  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink



# **VS-50WQ03FN-M3**

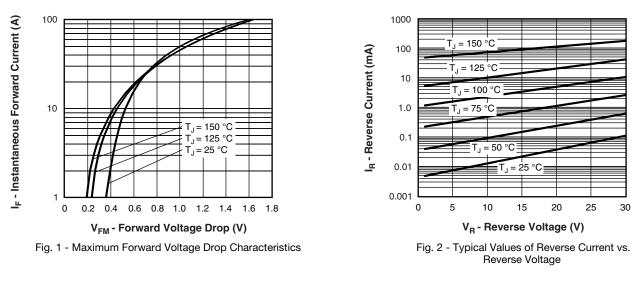
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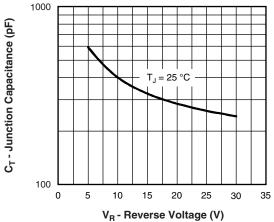


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

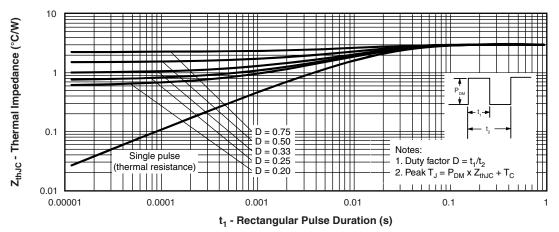


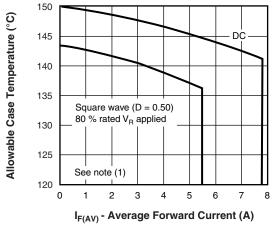
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

# **VS-50WQ03FN-M3**

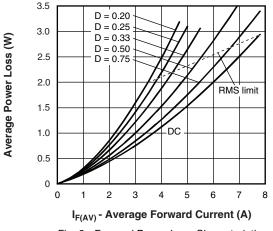
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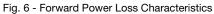
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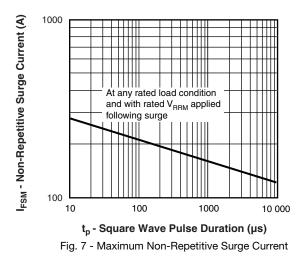












#### Note

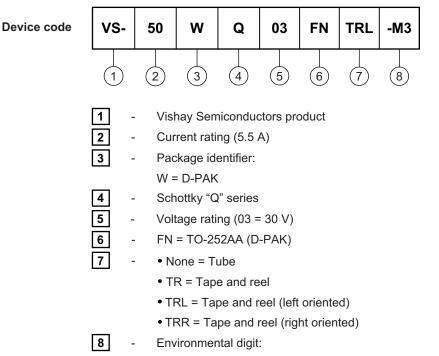
- (1)
- Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ; Pd = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6); Pd<sub>REV</sub> = Inverse power loss =  $V_{R1} \times I_R$  (1 D);  $I_R$  at  $V_{R1}$  = 80 % rated  $V_R$



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#### ORDERING INFORMATION TABLE



-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-50WQ03FN-M3	75	3000	Antistatic plastic tube						
VS-50WQ03FNTR-M3	2000	2000	13" diameter reel						
VS-50WQ03FNTRL-M3	3000	3000	13" diameter reel						
VS-50WQ03FNTRR-M3	3000	3000	13" diameter reel						

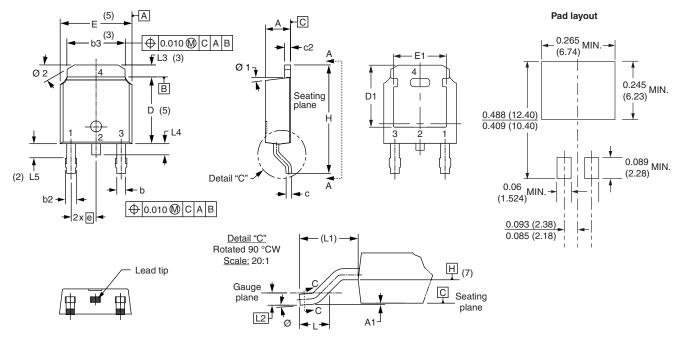
LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?95016</u>						
Part marking information	www.vishay.com/doc?95176					
Packaging information	www.vishay.com/doc?95033					



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# D-PAK (TO-252AA)

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094		е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005		Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035		L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045		L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3	L2	0.51	BSC	0.020	BSC	
с	0.46	0.61	0.018	0.024		L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035		L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5	L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3	Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5	Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3	Ø2	25°	35°	25°	35°	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension uncontrolled in L5

<sup>(3)</sup> Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

<sup>(4)</sup> Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(6)</sup> Dimension b1 and c1 applied to base metal only

<sup>(7)</sup> Datum A and B to be determined at datum plane H

<sup>(8)</sup> Outline conforms to JEDEC outline TO-252AA

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